NSN 5962-01-029-5083

Memory Microcircuit - Page 1 of 1



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- 0.440 inches
- **Body Width:**

0.285 inches

Body Height:

0.085 inches

Maximum Power Dissipation Rating:

715.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmed and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Input Circuit Pattern:

10 input

Current Rating Per Characteristic:

125.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds propagation delay time, high to low level output and 85.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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